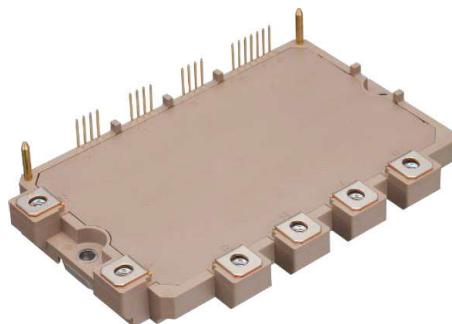
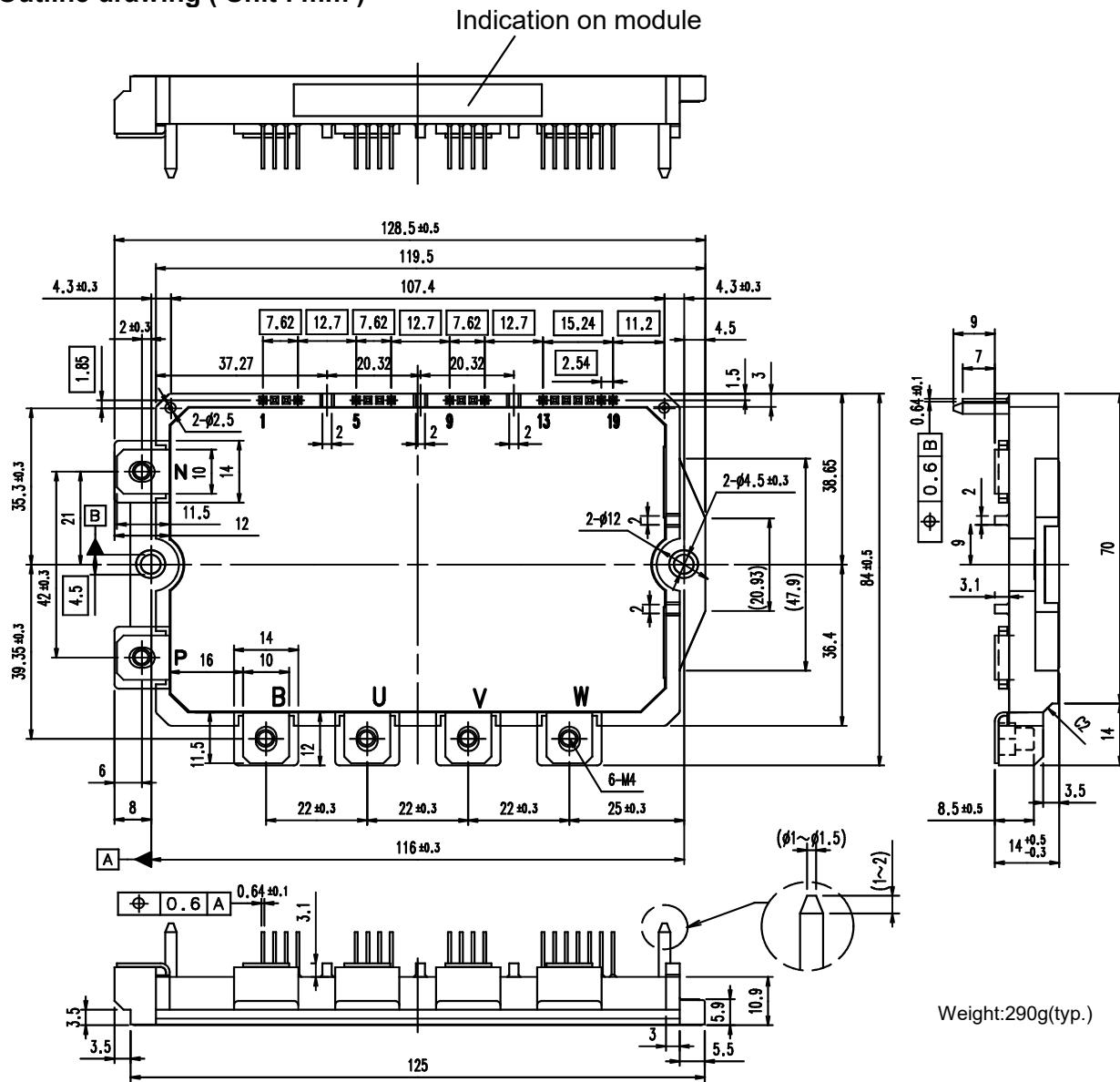


7MBP100XDN120-50

IGBT Modules
IGBT Module (X series)
1200V / 100A / IPM
■ Features

- Temperature protection provided by directly detecting the junction temperature of the IGBTs
- Low power loss and soft switching
- High performance and high reliability IGBT with overheating protection
- Higher reliability because of a big decrease in number of parts in built-in control circuit


■ Outline drawing (Unit : mm)


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IGBT Modules

■ Absolute maximum ratings

$T_C=25^\circ\text{C}$, $T_{vj}=25^\circ\text{C}$, $V_{CC}=15\text{V}$ unless otherwise specified

Items	Symbol	Conditions	Min.	Max.	Units
Collector-Emitter voltage	V_{CES}	*1	-	1200	V
Short circuit voltage	V_{SC}	*2	400	800	V
Inverter Collector current	I_C	DC	-	100	A
	I_{CP}	1ms	-	200	A
	$-I_C$	Duty=100% *3	-	100	A
Total power dissipation	P_{tot}	IGBT 1 device *4	-	652	W
Brake Repetitive peak reverse voltage	V_{RRM}	Diode part	-	1200	V
	I_C	DC	-	50	A
	I_{CP}	1ms	-	100	A
	I_F		-	50	A
Total power dissipation	P_{tot}	IGBT 1 device *4	-	416	W
Supply voltage of pre-driver	V_{CC}	*5	-0.5	20	V
Input signal voltage	V_{in}	*6	-0.5	$V_{CC}+0.5$	V
Alarm signal voltage	V_{ALM}	*7	-0.5	V_{CC}	V
Alarm signal current	I_{ALM}	*8	-	20	mA
Virtual junction temperature	T_{vj}		-	175	°C
Operating virtual junction temperature	T_{vjop}		-	150	°C
Operating case temperature	T_c		-20	125	°C
Storage temperature	T_{stg}		-40	125	°C
Solder temperature	T_{sol}	*9	-	260	°C
Isolating voltage	V_{isol}	*10	-	AC2500	Vrms
Mounting torque of screws to heat sink	M_s	Mounting(M4)	-	1.7	Nm
Mounting torque of screws to terminals	M_t	Main terminals(M4)	-	1.7	Nm

Notes

*1: V_{CES} shall be applied to the input voltage between terminal P-(U,V, W) and (U,V, W,B)-N.

*2: In the case of the load inductance to be over 1μH.

*3: Duty=150°C/ $R_{th(j-c)D}$ /($I_F \times V_F$ Max.)×100

*4: $P_{tot}=150^\circ\text{C}/R_{th(j-c)Q}$

*5: V_{CC} shall be applied to the input voltage between terminal No.4 and 1, 8 and 5, 12 and 9,14 and 13.

*6: V_{in} shall be applied to the input voltage between terminal No.3 and 1, 7 and 5, 11 and 9,15~18 and 13.

*7: V_{ALM} shall be applied to the voltage between terminal No.2 and 1 , 6 and 5 , 10 and 9 , 19 and 13.

*8: I_{ALM} shall be applied to the input current to terminal No.2,6,10 and 19.

*9: Immersion time 10±1sec. 1 time.

*10: Terminal to base, 50/60Hz sine wave 1 min. All terminals should be connected together during the test.

7MBP100XDN120-50

IGBT Modules

■ Electrical characteristics

● Main circuit

 $T_{vj}=25^\circ\text{C}$, $V_{CC}=15\text{V}$ unless otherwise specified

Item	Symbol	Conditions	Min.	Typ.	Max.	Units
Inverter	Collector current at off signal input	I_{CES} $V_{CE} = 1200\text{V}$	-	-	1.0	mA
	Collector-Emitter saturation voltage	$V_{CE(\text{sat})}$ $I_C = 100\text{A}$	Terminal	-	2.00	V
			Chip	-	1.45	V
Brake	Forward voltage of FWD	V_F $I_F = 100\text{A}$	Terminal	-	2.50	V
			Chip	-	1.90	V
	Collector current at off signal input	I_{CES} $V_{CE} = 1200\text{V}$	-	-	1.0	mA
Brake	Collector-Emitter saturation voltage	$V_{CE(\text{sat})}$ $I_C = 50\text{A}$	Terminal	-	1.8	V
			Chip	-	1.45	V
	Forward voltage of FWD	V_F $I_F = 50\text{A}$	Terminal	-	2.8	V
Switching time *11	t_{on}	$I_C = 100\text{A}$ $T_{vj}=150^\circ\text{C}$	0.5	-	-	μs
	$t_{d(on)}$	$V_{DC} = 600\text{V}$	0.5	-	-	μs
	t_{off}		-	-	2.0	μs
	$t_{d(off)}$		-	-	1.7	μs
	t_{rr}	$I_F = 100\text{A}$ $T_{vj}=150^\circ\text{C}$	-	-	0.5	μs

*11: Turn on time (t_{on}) = $t_{d(on)}$ + t_r , Turn off time (t_{off}) = $t_{d(off)}$ + t_f

● Control circuit

 $T_{vj}=25^\circ\text{C}$, $V_{CC}=15\text{V}$ unless otherwise specified

Item	Symbol	Conditions	Min.	Typ.	Max.	Units
Supply current of P-side pre-driver (per one unit)	I_{ccp}	Switching frequency (f_{SW}) = 0~15kHz $T_C = -20\sim 125^\circ\text{C}$	-	-	16	mA
Supply current of N-side pre-driver	I_{ccn}		-	-	55	mA
Input signal threshold voltage	$V_{inth(on)}$	$V_{in}-\text{GND}$	ON	1.2	1.4	1.6
	$V_{inth(off)}$		OFF	1.5	1.7	1.9

● Protection circuit

 $T_{vj}=25^\circ\text{C}$, $V_{CC}=15\text{V}$ unless otherwise specified

Item	Symbol	Conditions	Min.	Typ.	Max.	Units
Over current protection level	Inverter	I_{oc} $T_{vj}=150^\circ\text{C}$ Resistance load	150	-	-	A
	Brake		75	-	-	A
Over current protection delay time	t_{dOC}	$T_{vj}=150^\circ\text{C}$	-	4.0	-	μs
Short circuit protection delay time	t_{dSC}	$T_{vj}=150^\circ\text{C}$	-	1.0	-	μs
IGBT chips over heating protection temperature level	T_{jOH}	Surface of IGBT chips	175	-	-	°C
Over heating protection hysteresis	T_{jh}		-	20	-	°C
Under voltage protection level	V_{UV}		11.0	-	12.5	V
Under voltage protection hysteresis	V_H		0.2	0.5	-	V
Alarm signal hold time	$t_{ALM(OC)}$	ALM-GND $T_C=-20\sim 125^\circ\text{C}$	1.0	2.0	2.4	ms
	$t_{ALM(UV)}$		3.5	4.0	4.5	ms
	$t_{ALM(TjOH)}$		7.0	8.0	9.0	ms
Alarm signal voltage	V_{ALMH}	ALM-GND, without protection	14.5	-	15.0	V
Resistance for current limit	R_{ALM}		960	-	1570	Ω

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IGBT Modules

■ Thermal resistance characteristics ($T_c = 25^\circ\text{C}$)

Item			Symbol	Min.	Typ.	Max.	Units
Thermal resistance junction to case *12	Inverter	IGBT	$R_{th(j-c)Q}$	-	-	0.23	K/W
		FWD	$R_{th(j-c)D}$	-	-	0.33	K/W
	Brake	IGBT	$R_{th(j-c)Q}$	-	-	0.36	K/W
		FWD	$R_{th(j-c)D}$	-	-	0.64	K/W
Thermal resistance case to heat sink *13			$R_{th(c-s)}$	-	0.05	-	K/W

*12: For 1 device , the measurement point of the case is just under the chip.

*13: This is the value which is defined mounting on the additional heat sink with 1 W/(m·K) thermal grease.

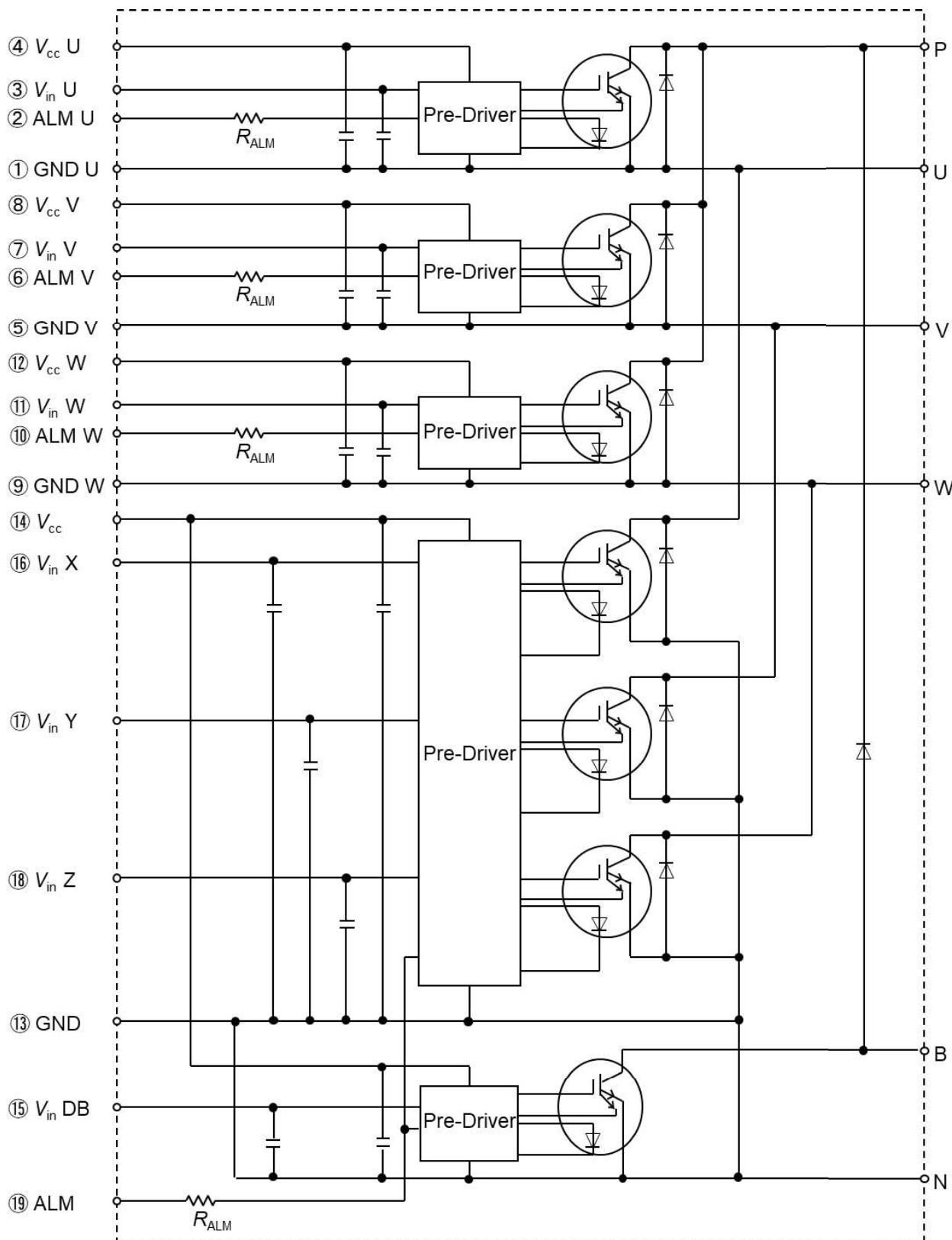
■ Noise immunity ($V_{DC}=300V$, $V_{CC}=15V$)

Item	Conditions	Min.	Typ.	Max.	Units
Common mode rectangular noise	Pulse width 1μs,polarity ±10min. Judge : no over-current, no miss operating	±2.0	-	-	kV

■ Recommended operating conditions

Item	Symbol	Min.	Typ.	Max.	Units
DC bus voltage	V_{DC}	-	-	800	V
Power supply voltage of pre-driver	V_{CC}	13.5	15.0	16.5	V
Switching frequency of IPM	f_{sw}	-	-	20.0	KHz
Arm shoot through blocking time for IPM's input signal *14	t_{dead}	1.5	-	-	μs
Screw torque (M4)	-	-	1.3	-	1.7
*14: $t_{dead} = t_{off} - t_{d(on)}$					

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IGBT Modules
■ Block diagram


Pre-drivers include following functions

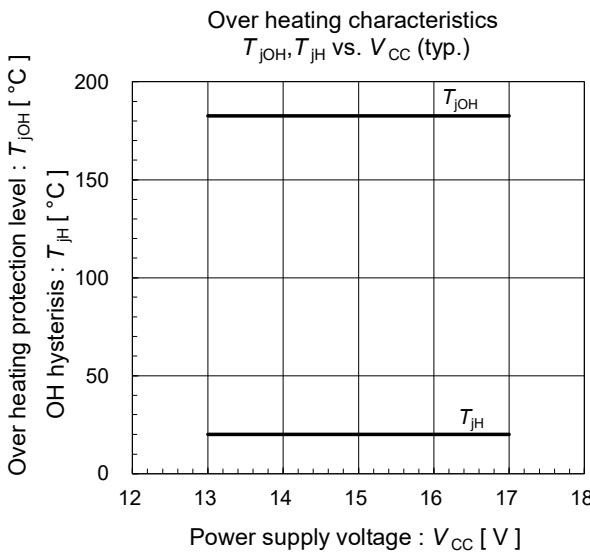
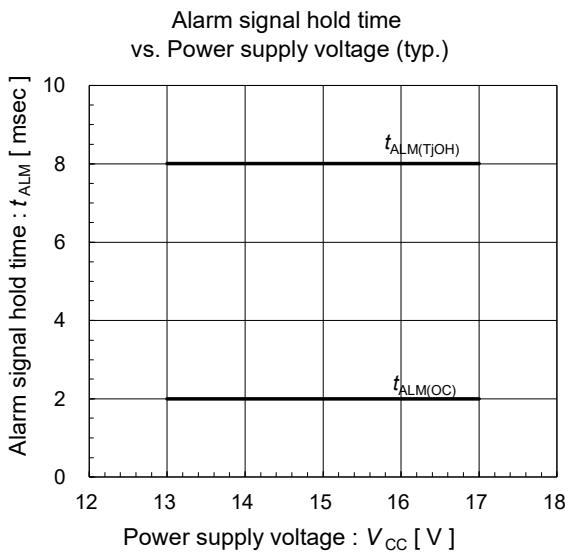
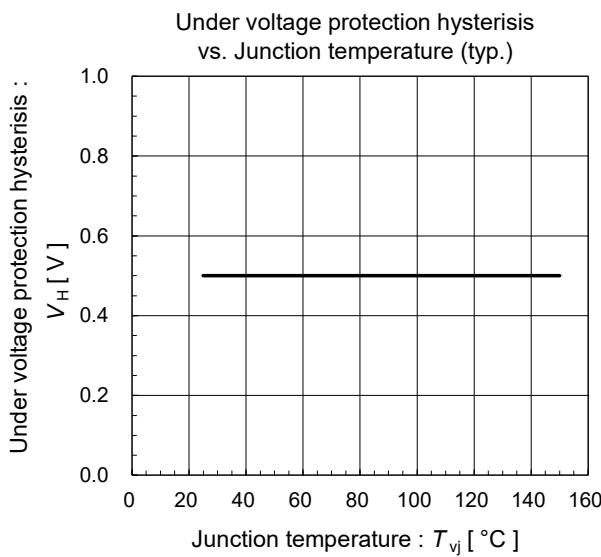
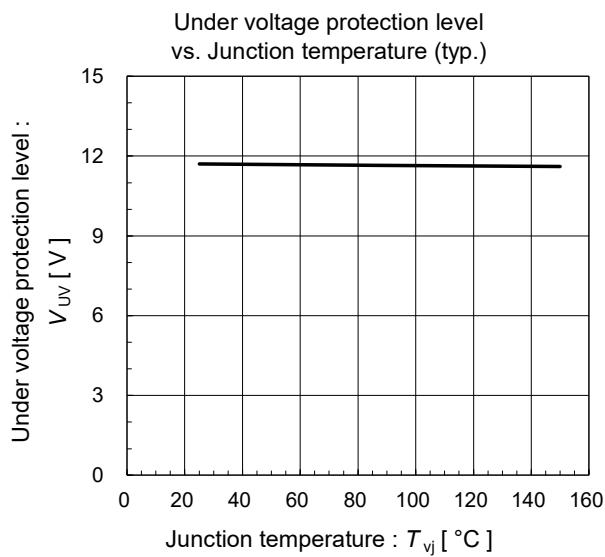
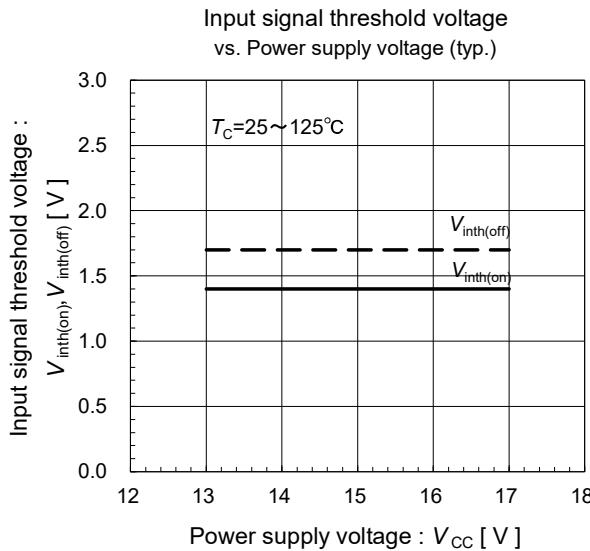
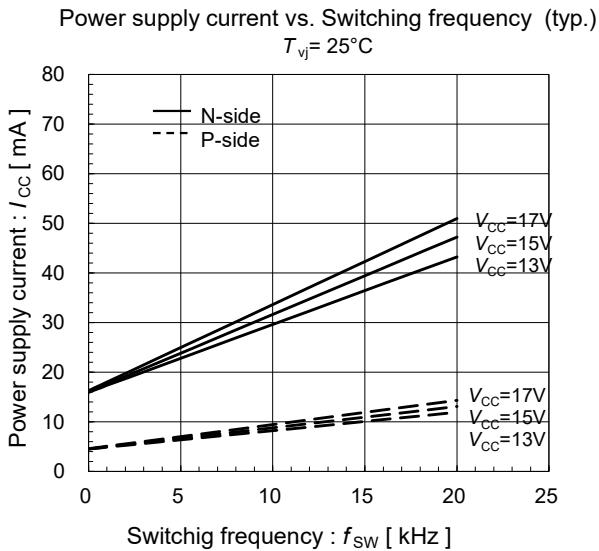
1. Amplifier for driver
2. Short circuit protection
3. Under voltage lockout circuit
4. Over current protection
5. IGBT chip over heating protection

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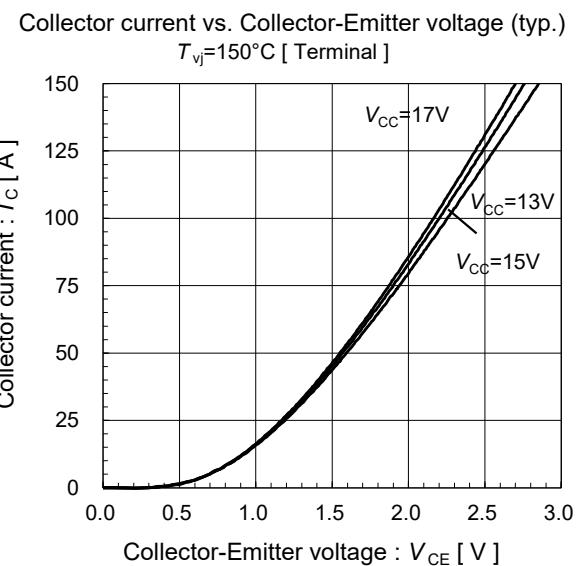
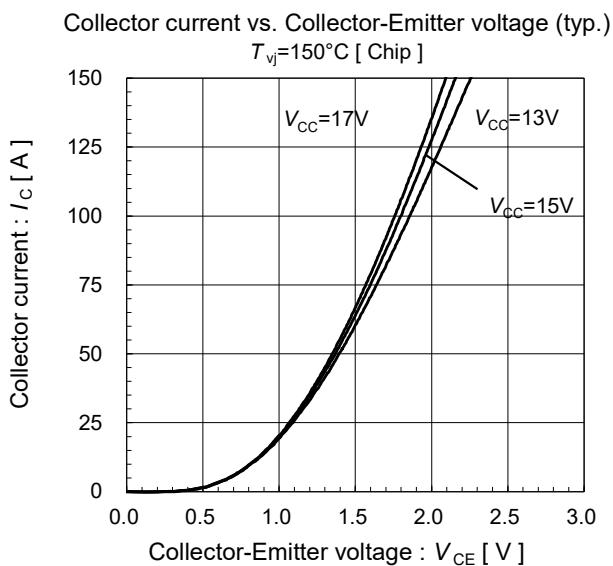
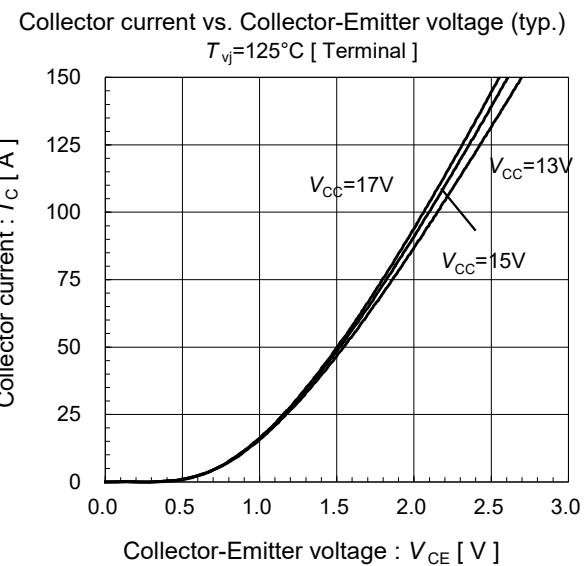
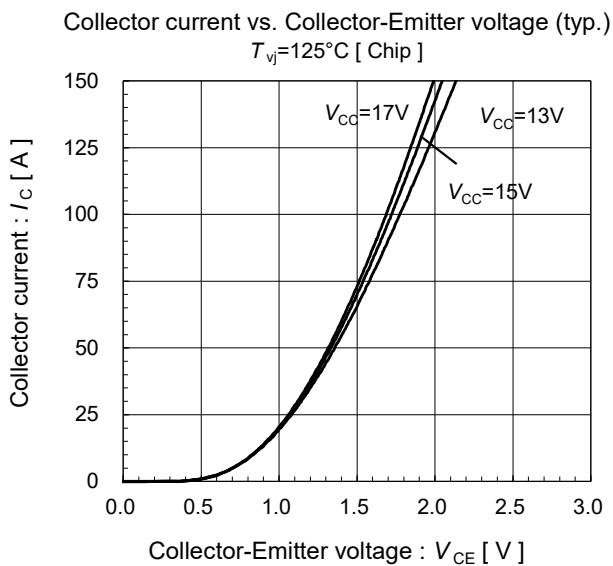
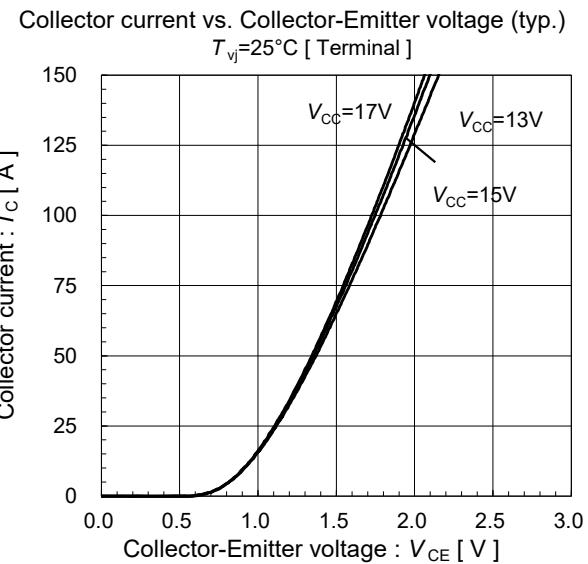
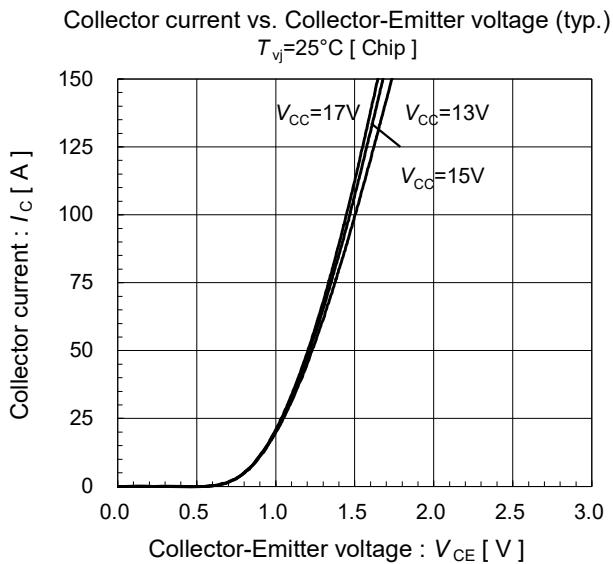
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■ Characteristics (representative)

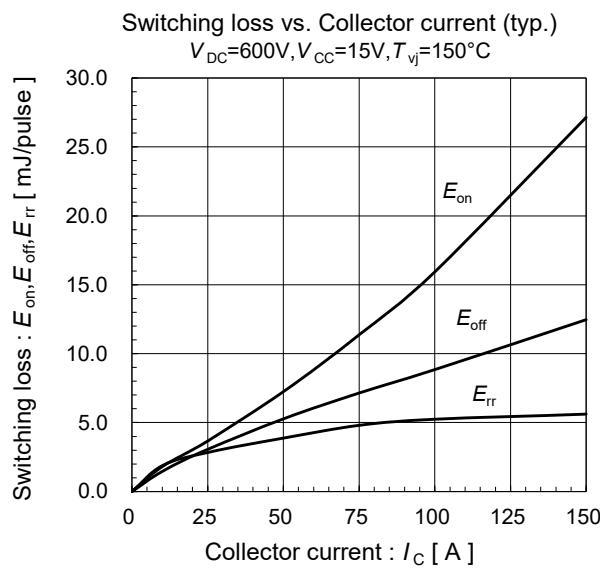
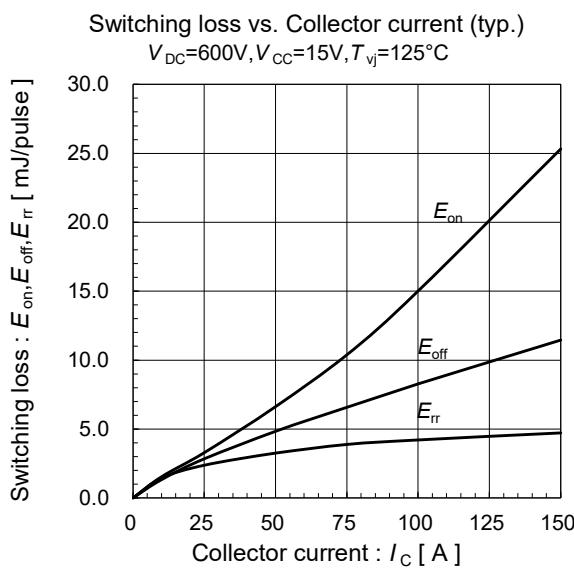
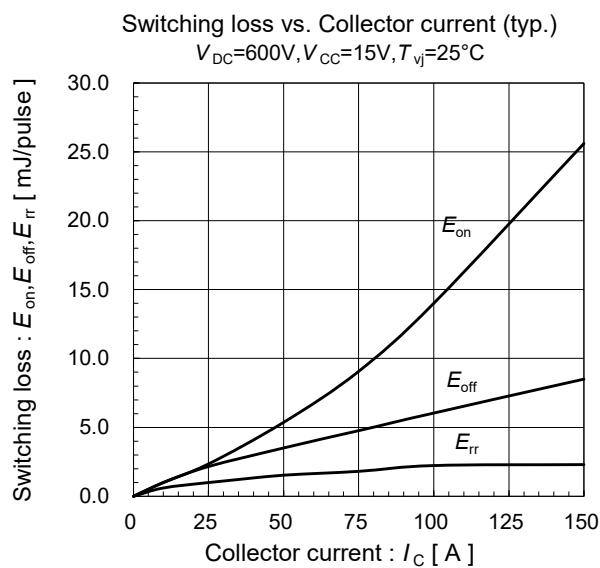
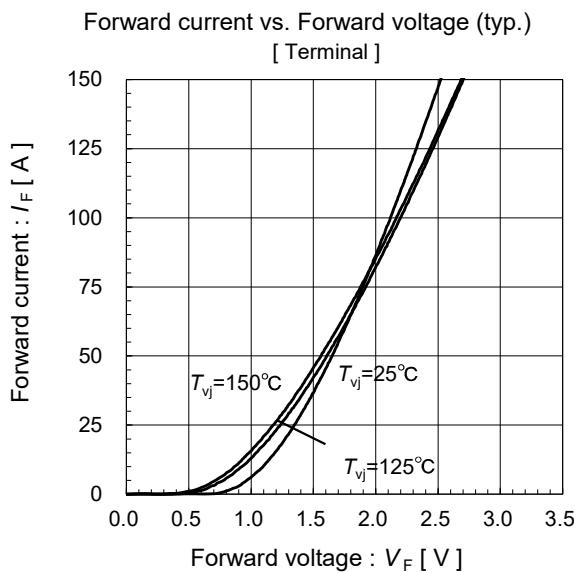
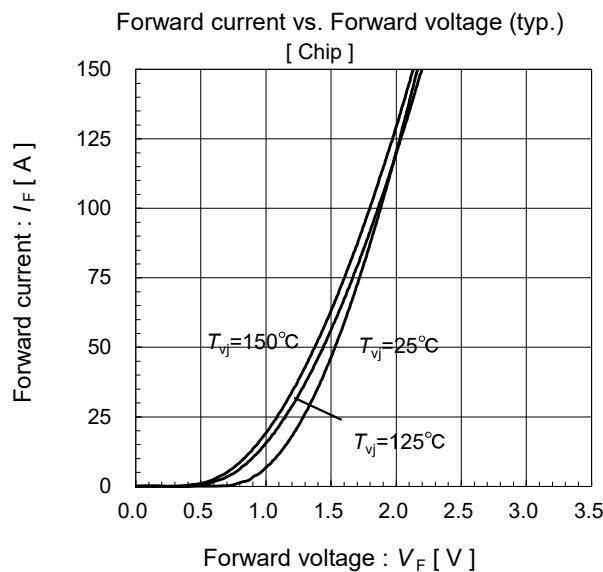
- Control circuit



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IGBT Modules
● Inverter


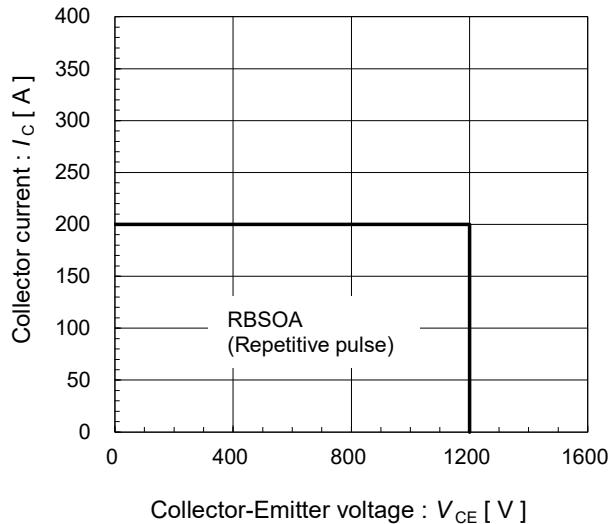
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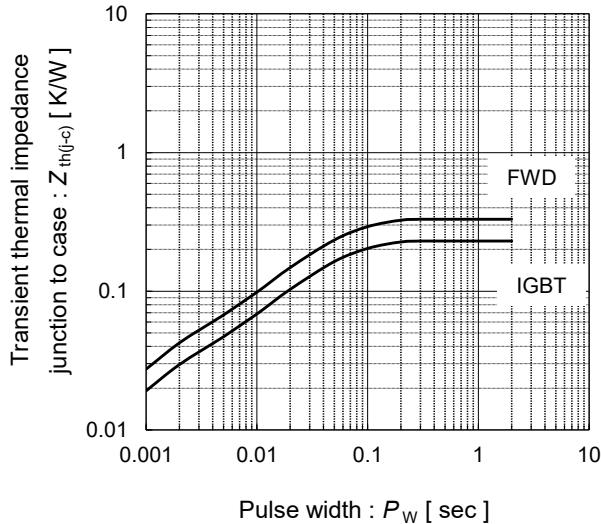
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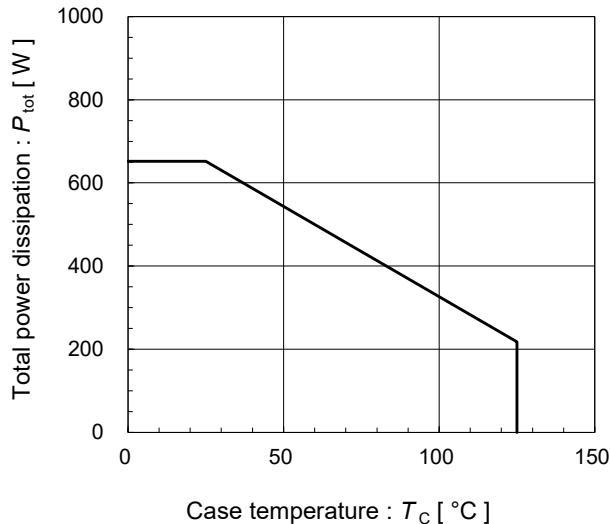
Reversed biased safe operating area (max.)
 $V_{CC}=15V, T_{vj}=150^{\circ}C$



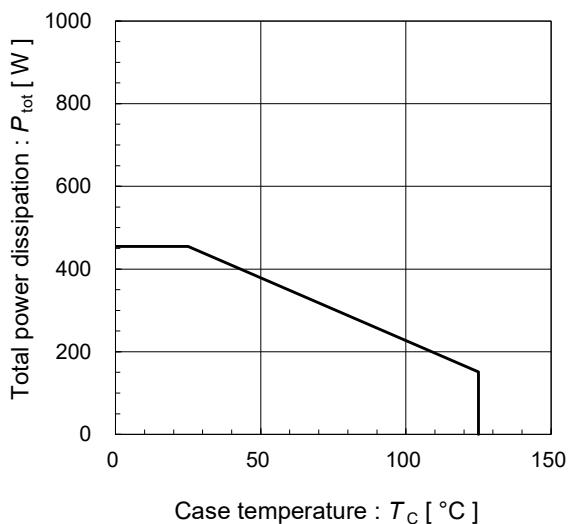
Transient thermal resistance (max.)



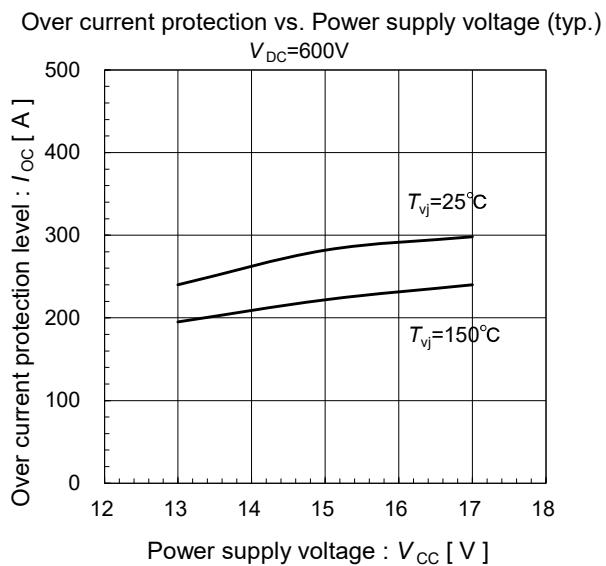
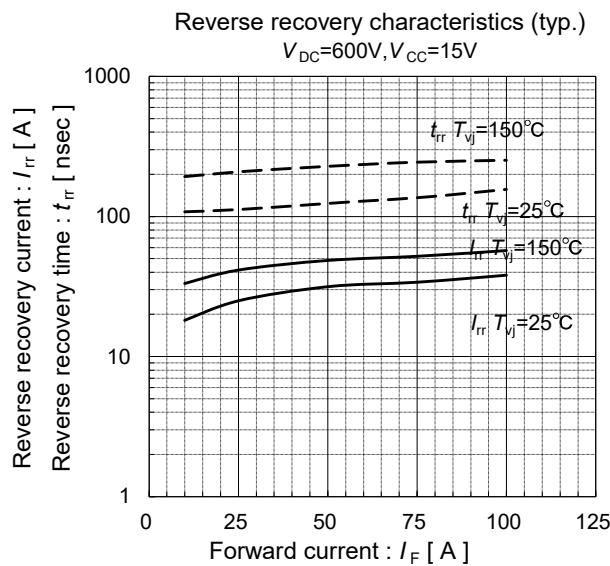
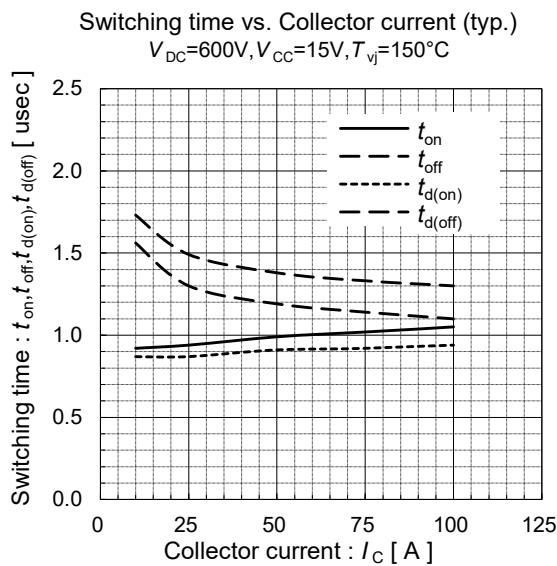
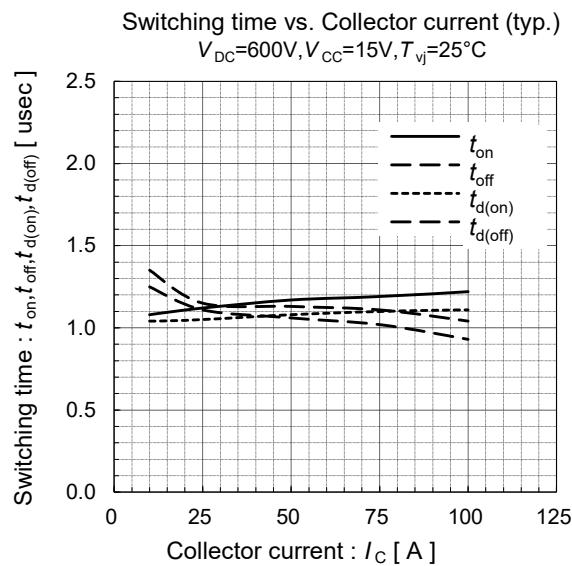
Power derating for IGBT (max.)
[per device]



Power derating for FWD (max.)
[per device]



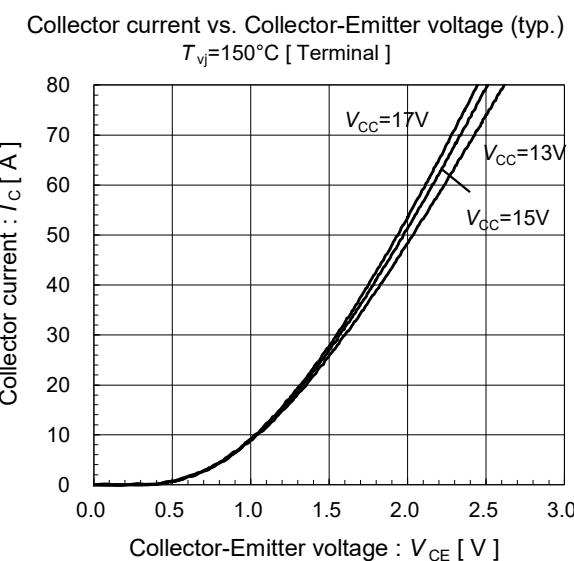
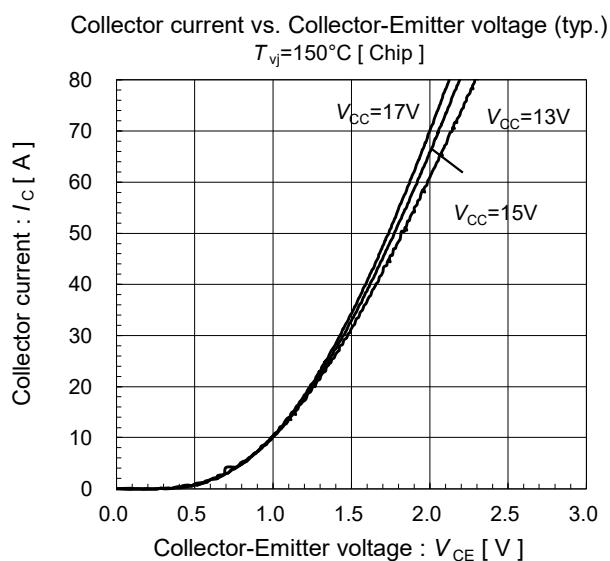
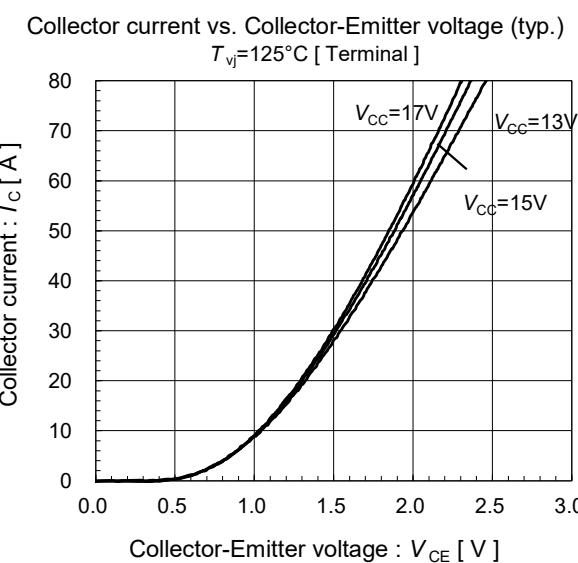
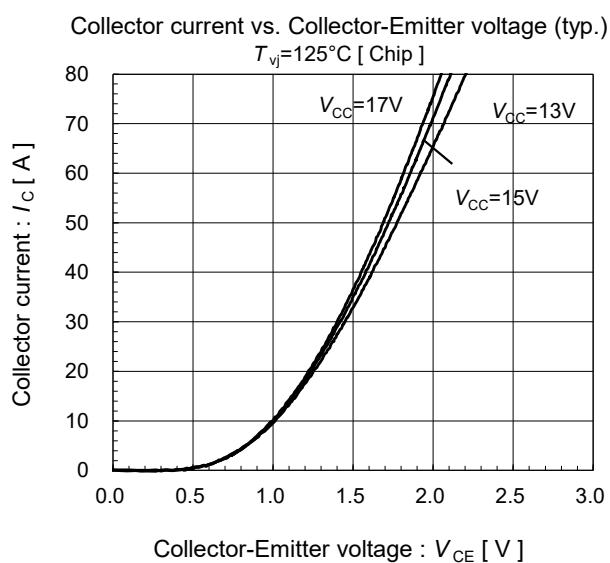
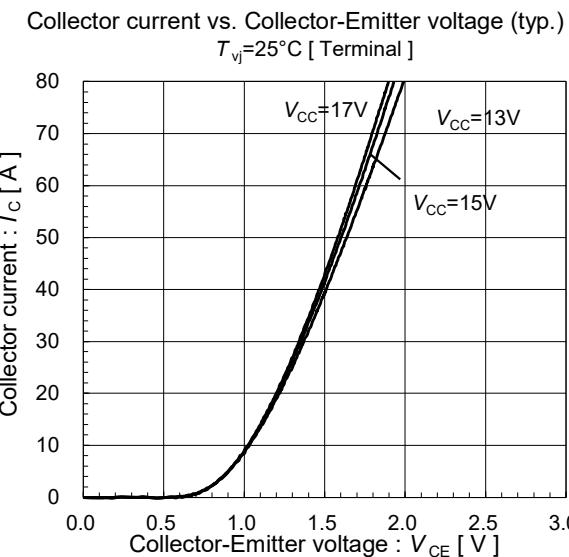
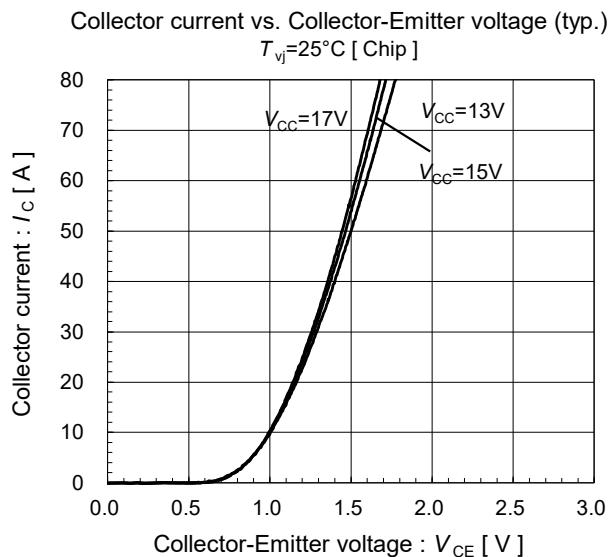
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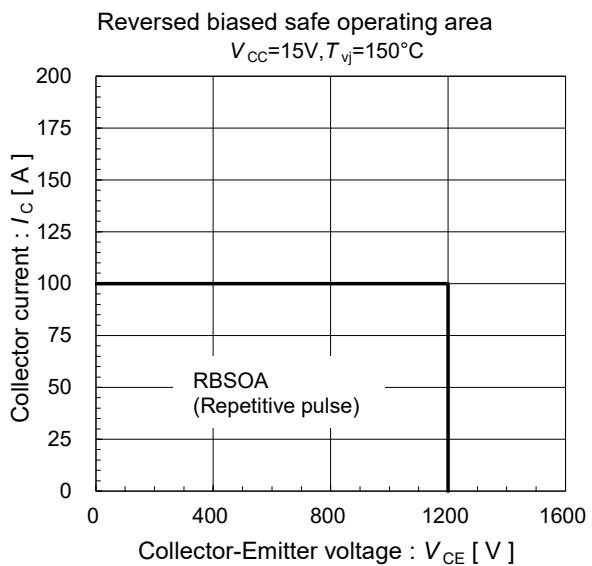
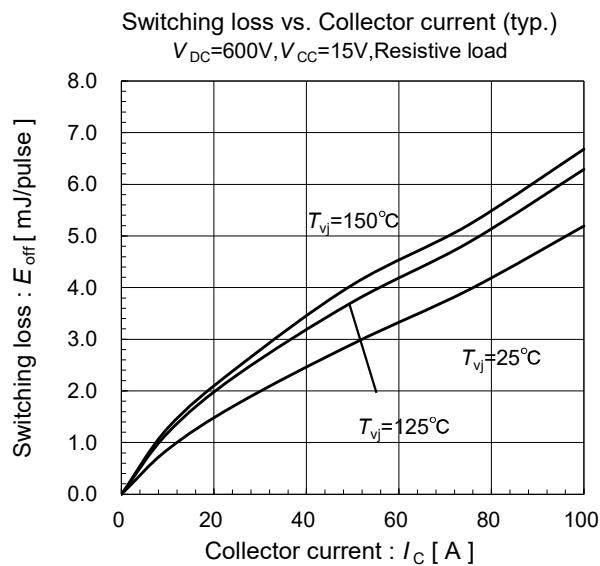
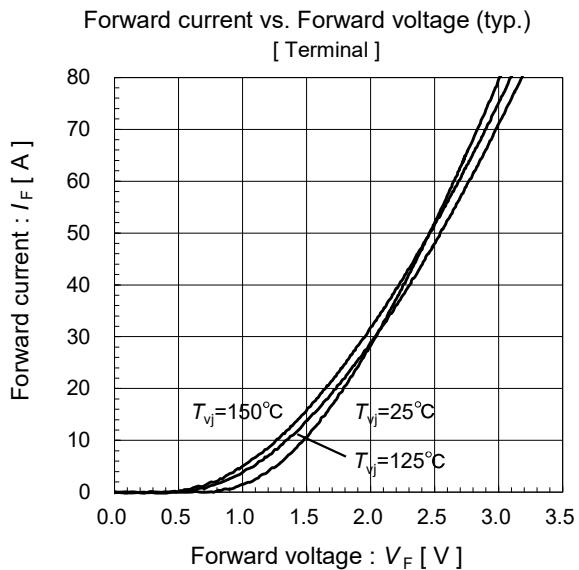
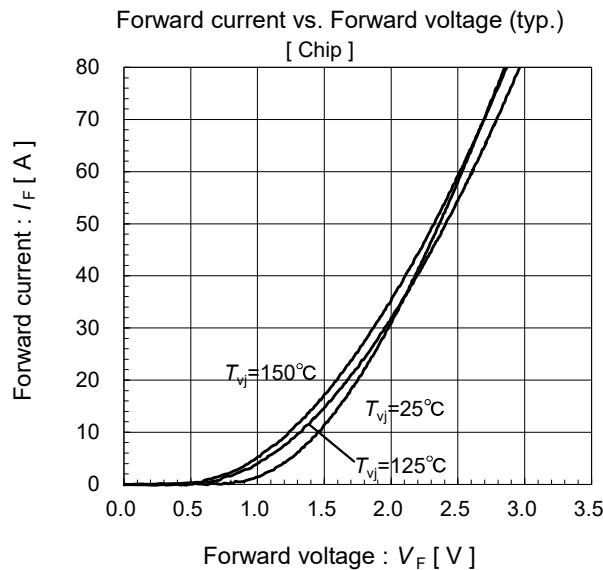
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IGBT Modules

● Brake

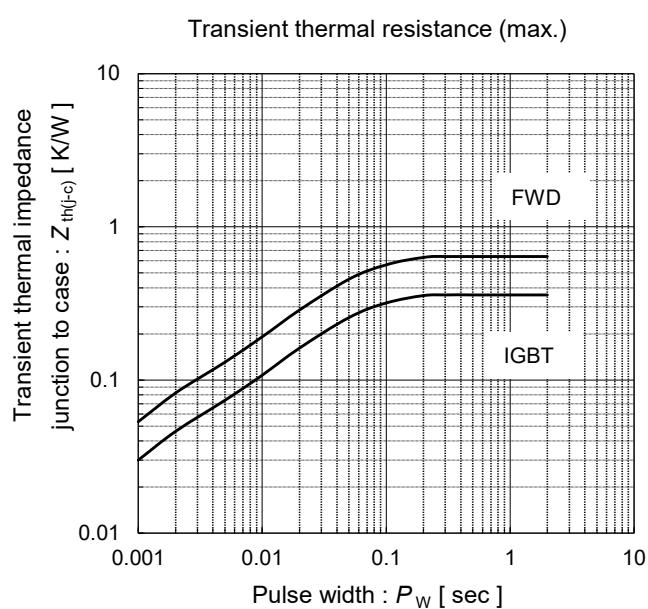
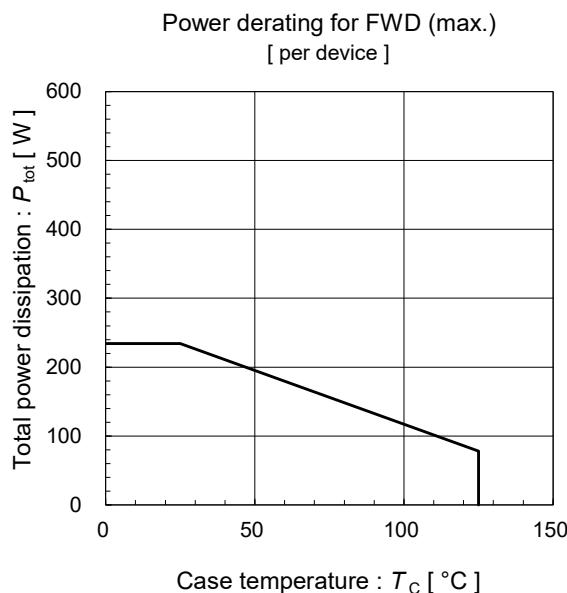
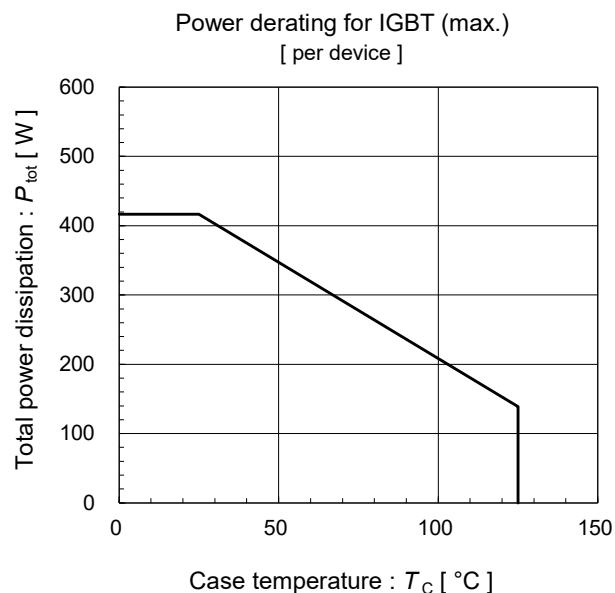


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IGBT Modules


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IGBT Modules



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IGBT Modules

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